

Superconducting dome in MoS₂ and TiSe₂ generated by quasiparticle-phonon coupling

Tanmoy Das and Kapildeb Dolui

Graphene Research Center and Department of Physics, National University of Singapore, 2 Science Drive 3, Singapore 117542

(Received 5 August 2014; revised manuscript received 9 March 2015; published 20 March 2015)

We use a first-principles based self-consistent momentum-resolved density fluctuation (MRDF) model to compute the combined effects of electron-electron and electron-phonon interactions to describe the superconducting dome in the correlated MoS₂ thin flake and TiSe₂. We find that without including the electron-electron interaction, the electron-phonon coupling and the superconducting transition temperature (T_c) are overestimated in both these materials. However, once the full angular and dynamical fluctuations of the spin and charge density induced quasiparticle self-energy effects are included, the electron-phonon coupling and T_c are reduced to the experimental value. With doping, both electronic correlation and electron-phonon coupling grows, and above some doping value, the former becomes so large that it starts to reduce the quasiparticle-phonon coupling constant and T_c , creating a superconducting dome, in agreement with experiments.

DOI: [10.1103/PhysRevB.91.094510](https://doi.org/10.1103/PhysRevB.91.094510)

PACS number(s): 74.20.Fg, 73.22.-f, 74.78.Na

I. INTRODUCTION

Unconventional superconductivity in cuprates, pnictides, and heavy fermions often reaches its optimum value near the quantum critical point (QCP) of a magnetic ground state, providing a perspective that critical phase fluctuations of the intertwined electronic order drive unconventional superconductivity [1]. However, looking back at conventional superconductors, a superconducting (SC) dome is not an unfamiliar feature. It has been observed in Li metal under pressure [2], doped SrTiO₃ [3] gated LaAlO₃/SrTiO₃ (LAO/STO) interface [4], pressure tuned Fe metal [5], and also in TSe_2 ($T = \text{Ti, Ta, and Nb}$) families [6–9], and more recently in a thin flake of MoS₂ [10,11]. More interestingly, no evidence of an intertwined electronic order in the SC state is reported in these materials, except in TSe_2 . The possible role of the charge density wave (CDW) in the SC dome in the latter family has also recently been called into question by a pressure dependent x-ray scattering measurement [12], because the QCP of CDW in $1T\text{-TiSe}_2$ lies at a higher pressure than the termination of the SC dome. Therefore, the presence of a SC dome with and without an intervening QCP leads to the fundamental question: Can there be an alternative and universal origin of the SC dome which is applicable to all families of superconductors?

We explore the possible role of the momentum dependent density fluctuations (MRDF) in renormalizing the electronic pairing strength and thereby producing optimized SC transition temperature (T_c) as a function of doping. Spin and charge fluctuations are among the two dominant electron-electron (EE) correlations which are ubiquitous in weakly to strongly correlated materials, irrespective of the formation of a static electronic order [13,14]. These fluctuations renormalize the quasiparticle states, which in turn renormalizes the electron-phonon (EP) or more appropriately quasiparticle-phonon coupling strength and vice versa. In this work we present a self-consistent theory for the combined EE and EP interaction to calculate the electronic self-energy for the band renormalization, the renormalized EP coupling spectral function α^2F , and T_c (see Fig. 1 for these results in MoS₂), starting from the materials specific first-principles band structure. We find that the interplay between the EE and EP coupling has a common role in reproducing the SC dome as a function of doping in both MoS₂ [11] and TiSe₂ [6] samples.

The rest of the paper is organized as follows. In Sec. II we present the methodology which includes the details of DFT calculation in Sec. II A, the MRDF method of calculating momentum dependent density-density fluctuation and self-energy in Sec. II B, and the quasiparticle-phonon coupling constant and T_c calculations in Sec. II C, and finally the relevant parameters in Sec. II D. The results of band structure, α^2F , and T_c are presented in Sec. III for a MoS₂ thin flake and for bulk TiSe₂. Finally, we conclude in Sec. IV. Some additional results such as spin and charge fluctuations, momentum dependent self-energies, doping dependent mass renormalizations, ω_{\log} , and μ^* are presented in the Appendixes.

II. METHOD

A. Density function theory calculation

Electronic structure calculations are carried out using density functional theory (DFT) within the local density approximations (LDA) in the Ceperley-Alder parametrization [15] for an exchange-correlation functional as implemented in the Vienna *ab initio* simulation package (VASP) [16]. Projected augmented-wave (PAW) [17] pseudopotentials are used to describe core electrons. The conjugate gradient method is used to obtain relaxed geometries. Both atomic positions and cell parameters are allowed to relax, until the forces on each atom are less than 1 meV/Å. The relaxed lattice parameters are $a = b = 3.121 \text{ \AA}$, $c/a=3.868$ (bilayer distance) for MoS₂, and $a = b = 3.437 \text{ \AA}$, $c/a=1.693$ for TiSe₂.

The kinetic energy cutoff is fixed at 650 eV. Γ centered k -mesh grids of $14 \times 14 \times 1$ and $14 \times 14 \times 8$ are used in the self-consistent calculations for MoS₂ and TiSe₂, respectively. Note that we did not consider any van der Waals (vdW) correction in our calculations, as the previous vdW+DFT calculations show that bilayer MoS₂ exhibits an indirect gap between the Γ and K direction, which contradicts GW calculations [18,19]. However, our calculated LDA band structure correctly describes this feature. Spin-orbit correction (SOC) is included in the band structure calculations. We note that for bilayer MoS₂, the SOC is significantly reduced due to the presence of the inversion symmetry [20]. Furthermore, in order to study the lattice dynamics, force constants are calculated for $3 \times 3 \times 1$ and $3 \times 3 \times 2$ supercells of MoS₂ and TiSe₂, respectively, within the framework of density

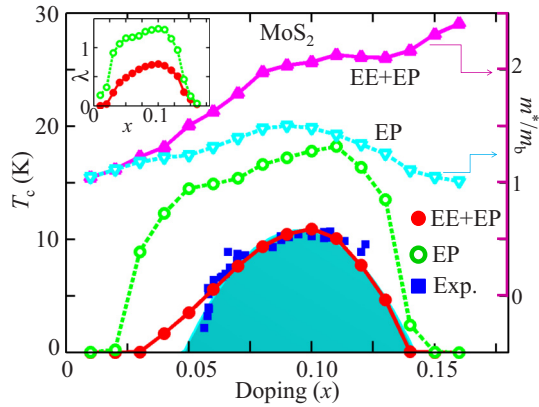


FIG. 1. (Color online) SC phase diagram of a thin flake of MoS₂. Blue squares are experimental T_c data, taken from Ref. [11]. Red filled circles give computed T_c by including self-consistent EE and EP interactions. Green open circles give the EP coupling induced T_c when the EE interaction is ignored. Magenta filled triangles and cyan open triangles, respectively, are the computed mass renormalizations for the corresponding two cases. Light blue shading is a guide to the eyes to the experimental SC dome. Inset: EP coupling constant (λ) when EE interaction is included (red filled circles) and ignored (green open circles).

functional perturbation theory [21] using the VASP code. Subsequently, phonon dispersions are calculated using the Phonopy package [22].

The band structure for monolayer and bilayer MoS₂ has significant differences [23,24]. In the monolayer system, both the conduction band bottom and the valence band top lie at the K point. In the bilayer system, the bottom of the conduction band shifts to somewhere in between the Γ and K points, and the top of the valence band moves to the Γ point. However, from the bilayer to the bulk system, the band structure does not change significantly. Therefore, given that the experiment is performed on a thin flake of MoS₂ sample, we use the band structure for the bilayer system.

The band dispersion between LDA and LDA+ GW calculation does not change characteristically [19,24], which means the doping dependence of the density of states would also be similar for both cases at the expense of a constant energy shift. Therefore, our many-body and T_c calculations would yield similar results for the LDA and LDA+ GW band structure inputs.

Finally, we have used a rigid band shift for the DFT dispersion, whereas with the self-energy correction, the new Fermi level is recalculated self-consistently. For MoS₂, the carrier density is monitored experimentally by gating, which is more appropriately modeled by a rigid-band shift. A previous DFT calculation by one of the present authors [25] showed that even an absorption alkali metal can rigidly shift the Fermi level to the conduction band in the same way. For TiSe₂, the SC dome is observed experimentally by Cu intercalation. However, as shown in the same experimental paper (Fig. 5 of Ref. [6]), the Sommerfeld coefficient of the same sample changes almost linearly with doping. This result is consistent with our finding of the density of states at the Fermi level with EE+EP correlation [our Fig. 4(d)]. This supports that the rigid band shift method is applicable in this family as well.

B. Momentum resolved density fluctuation (MRDF) theory

The VASP band structure information is directly implemented within our MRDF code. The single-particle Green's function is defined as $\tilde{G}_0(\mathbf{k}, i\omega_n) = (i\omega_n \tilde{1} - \tilde{H})^{-1}$, where $i\omega_n$ is the Matsubara frequency for the fermions, and H is the noninteracting Hamiltonian constructed by downfolding the DFT bands into the low-energy energy levels. The explicit form of G is then obtained as

$$G_{mn}(\mathbf{k}, i\omega_n) = \sum_v \frac{\phi_{\mathbf{k},m}^v \phi_{\mathbf{k},n}^{v\dagger}}{i\omega_n - \xi_{\mathbf{k}}^v}. \quad (1)$$

Here \mathbf{k} and ω are the quasiparticle momentum and frequency, and \mathbf{q} and ω_p are the bosonic excitation momentum and frequency, respectively. $\phi_{\mathbf{k},m}^v$ is the eigenstate for the v th DFT band ($\xi_{\mathbf{k}}^v$), projected onto the m th orbital. The noninteracting density fluctuation susceptibility in the particle-hole channel represents joint density of states (JDOS), which can be calculated by convoluting the corresponding Green's function over the entire Brillouin zone (BZ) to obtain (spin and charge bare susceptibility are the same in the paramagnetic ground state) [26]

$$\chi_{0,mn}^{st}(\mathbf{q}, \omega_p) = -\frac{1}{\Omega_{\text{BZ}} \beta} \sum_{\mathbf{k}, n} G_{mn}(\mathbf{k}, i\omega_n) G_{st}(\mathbf{k}+\mathbf{q}, i\omega_n + \omega_p), \quad (2)$$

where $\beta = 1/k_B T$, k_B is the Boltzmann constant, and T is temperature. Ω_{BZ} is the electronic phase space volume. $f_{\mathbf{k}}^v$ and n_p are the fermion and boson occupation numbers, respectively. After performing the Matsubara summation over the fermionic frequency ω_n and taking analytical continuation to the real frequency as $\omega_n \rightarrow \omega + i\delta$, we get

$$\chi_{0,mn}^{st}(\mathbf{q}, \omega_p) = -\frac{1}{\Omega_{\text{BZ}}} \sum_{\mathbf{k}, v, v'} \phi_{\mathbf{k}+\mathbf{q},s}^{v\dagger} \phi_{\mathbf{k}+\mathbf{q},t}^v \phi_{\mathbf{k},n}^{v'} \phi_{\mathbf{k},m}^{v'\dagger} \times \frac{f_{\mathbf{k}+\mathbf{q}}^v - f_{\mathbf{k}}^{v'}}{\omega_p + i\delta - \xi_{\mathbf{k}}^{v'} + \xi_{\mathbf{k}+\mathbf{q}}^v}. \quad (3)$$

The interacting density-density correlation functions are computed within the random phase approximation (RPA) which includes multiband components of the electronic interaction including intra- and interorbital Coulomb interactions, U and V , as well as Hund's coupling J_H , and pair-exchange term J' :

$$H_{\text{int}} = \sum_{\mathbf{k}_1 - \mathbf{k}_4} \left\{ U \sum_m c_{\mathbf{k}_1, m \uparrow}^\dagger c_{\mathbf{k}_2, m \uparrow} c_{\mathbf{k}_3, m \downarrow}^\dagger c_{\mathbf{k}_4, m \downarrow} + \sum_{m < n, \sigma} [V c_{\mathbf{k}_1, m \sigma}^\dagger c_{\mathbf{k}_2, m \sigma} c_{\mathbf{k}_3, n \bar{\sigma}}^\dagger c_{\mathbf{k}_4, n \bar{\sigma}} + (V - J_H) c_{\mathbf{k}_1, m \sigma}^\dagger c_{\mathbf{k}_2, m \sigma} c_{\mathbf{k}_3, n \sigma}^\dagger c_{\mathbf{k}_4, n \sigma}] + \sum_{m < n, \sigma} (J_H c_{\mathbf{k}_1, m \sigma}^\dagger c_{\mathbf{k}_3, n \bar{\sigma}}^\dagger c_{\mathbf{k}_2, m \bar{\sigma}} c_{\mathbf{k}_4, n \sigma} + J' c_{\mathbf{k}_1, m \sigma}^\dagger c_{\mathbf{k}_3, m \bar{\sigma}}^\dagger c_{\mathbf{k}_2, n \bar{\sigma}} c_{\mathbf{k}_4, n \sigma} + \text{H.c.}) \right\}. \quad (4)$$

Here $c_{\mathbf{k}_1, m \sigma}^\dagger$ ($c_{\mathbf{k}_1, m \sigma}$) is the creation (annihilation) operator for an orbital m at crystal momentum \mathbf{k}_1 with spin $\sigma = \uparrow$ or \downarrow ,

where $\bar{\sigma}$ corresponds to opposite spin of σ . In the multiorbital spinor, the above interacting Hamiltonian can be collected in a interaction tensor $\tilde{U}_{s/c}$, where the subscripts s and c stand for spin and charge density fluctuations. The nonzero components of the matrices \tilde{U}_c and \tilde{U}_s are given as [26,27]

$$\begin{aligned}\tilde{U}_{s,mm}^{mm} &= U, & \tilde{U}_{s,nn}^{mm} &= \frac{1}{2}J_H, \\ \tilde{U}_{s,nn}^{mn} &= \frac{1}{4}J_H + V, & \tilde{U}_{s,nn}^{nm} &= J', \\ \tilde{U}_{c,mm}^{mm} &= U, & \tilde{U}_{c,nn}^{mm} &= 2V, \\ \tilde{U}_{c,nn}^{mn} &= \frac{3}{4}J_H - V, & \tilde{U}_{c,nn}^{nm} &= J'.\end{aligned}\quad (5)$$

Of course it is implicit that all the interaction parameters are orbital dependent. Within the RPA, spin and charge channels become decoupled. The collective many-body corrections of the density-fluctuation spectrum can be written in matrix representation: $\tilde{\chi}_{s/c} = \tilde{\chi}^0[\tilde{1} \mp \tilde{U}_{s/c}\tilde{\chi}^0]^{-1}$, for spin and charge densities, respectively. $\tilde{\chi}^0$ matrix consists of components $\chi_{0,mm}^{st}$ with the same basis in which the interactions $\tilde{U}_{s/c}$ are defined above.

The interaction parameters (U , V , J_H , and J') are not parametrized individually. Rather, we estimate the components of the interaction matrices $\tilde{U}_{s/c}$ within the Kanamori criterion $\tilde{U}_s \leq \{\max[\tilde{\chi}'_0(\mathbf{q}, 0)]\}^{-1}$, and $\tilde{U}_s = \tilde{U}_c$, and set the values at the optimal doping for each system. Note that in the self-consistent loop when the self-energy is included in $\tilde{\chi}'_0$, the corresponding values of U effectively include the screening phenomena due to spin, charge, and phonon scatterings.

Finally, the EE interaction potentials for the electronic state are computed as

$$V_{mn,i}^{st}(\mathbf{q}, \omega_p) = \frac{\eta_i}{2}[\tilde{U}_i \tilde{\chi}'_i(\mathbf{q}, \omega_p) \tilde{U}_i]_{mn}^{st}, \quad (6)$$

where i stands for spin and charge components, $\eta = 3, 1$ for the spin and charge channels, respectively. The electron-phonon coupling effect is calculated similarly:

$$V_{mn,p}^{st}(\mathbf{q}, \omega_p) = \sum_{\mathbf{k}, \mu} |g_{ms}^\mu(\mathbf{k}, \mathbf{q})| |g_{nt}^\mu(\mathbf{k}, \mathbf{q})| \delta(\omega_p - \omega_{q\mu}), \quad (7)$$

where $\omega_{q\mu}$ is the phonon dispersion for band μ , and the subscript p stands for the EP term. The EP coupling matrix element is $g_{ij}^\mu(\mathbf{k}, \mathbf{q}) = \sum_v g_{\mathbf{q}, 0}^\mu \phi_{\mathbf{k}, i}^{v\dagger} \phi_{\mathbf{k}+\mathbf{q}, i}^v$, where the momentum averaged EP scattering amplitude g_0 is deduced from the first-principles calculation.

The feedback effect of the two EE potentials, and the EP coupling on the electronic spectrum, is then calculated via self-energy calculation within the MRDF method [14,28,29]

$$\begin{aligned}\Sigma_{mn,i}(\mathbf{k}, \omega) &= \frac{1}{\Omega_{\text{BZ}}} \sum_{\mathbf{q}, st, v} \int_{-\infty}^{\infty} d\omega_p V_{mn,i}^{st}(\mathbf{q}, \omega_p) \Gamma_{mn,v}^{st}(\mathbf{k}, \mathbf{q}) \\ &\times \left[\frac{1 - f_{\mathbf{k}-\mathbf{q}}^v + n_p}{\omega + i\delta - \xi_{\mathbf{k}-\mathbf{q}}^v - \omega_p} \right. \\ &\left. + \frac{f_{\mathbf{k}-\mathbf{q}}^v + n_p}{\omega + i\delta - \xi_{\mathbf{k}-\mathbf{q}}^v + \omega_p} \right],\end{aligned}\quad (8)$$

where the subscript i stands for spin, charge, and phonon contributions. The vertex correction $\Gamma_{mn,v}^{st}(\mathbf{k}, \mathbf{q})$ encodes both the angular and dynamical parts of the vertex, which are

combined to obtain $\Gamma_{mn,v}^{st}(\mathbf{k}, \mathbf{q}) = \phi_{\mathbf{k}-\mathbf{q}, s}^{v\dagger} \phi_{\mathbf{k}-\mathbf{q}, t}^v [1 - \partial \Sigma_{mn}(\mathbf{k} - \mathbf{q}, \omega) / \partial \omega]_0$. Full self-consistency requires the bare Green's function G_0 in Eq. (1) to be replaced with the self-energy dressed $\tilde{G}^{-1}(\mathbf{k}, \omega) = \tilde{G}_0^{-1}(\mathbf{k}, \omega) - \tilde{\Sigma}(\mathbf{k}, \omega)$, where the total self-energy tensor is $\tilde{\Sigma}(\mathbf{k}, \omega) = \tilde{\Sigma}_s(\mathbf{k}, \omega) + \tilde{\Sigma}_c(\mathbf{k}, \omega) + \tilde{\Sigma}_p(\mathbf{k}, \omega)$, and calculate susceptibilities and self-energies with the dressed Green's function until the self-energies converges. This procedure is numerically expensive, especially in the multiband systems and when full momentum dependence is retained. Therefore, we adopt a modified self-consistency scheme, where we expand the real part of the total self-energy tensor as $\tilde{\Sigma}'(\mathbf{k}, \omega) = (1 - \tilde{Z}_{\mathbf{k}})^{-1} \omega$ in the low-energy region [$|\omega| < 0.2\text{--}0.3$ eV in the present materials]. The resulting self-energy dressed quasiparticle dispersions $\tilde{\xi}^v(\mathbf{k}) = Z_{\mathbf{k}}^v \xi^v(\mathbf{k})$ are used in Eqs. (1)–(8), which keep all the formalism unchanged with respect to the momentum resolved orbital selective quasiparticle renormalization factor $\tilde{Z}_{\mathbf{k}}$.

C. Quasiparticle-phonon coupling and T_c calculation

In the systems where the interaction strength is of the order of the bandwidth, i.e., the kinetic and potential energies are of the same order, various instabilities develop. Different materials having different lattice structure and Fermi surface topology are prone to different forms of instabilities, among which leading contributions usually arise from the superconductivity and density wave fluctuations in the spin, charge, and lattice sectors. These instabilities often lead to an incoherent, or a gapped Fermi surface at the expense of superconductivity and/or a static density wave (s).

Therefore, even for conventional superconductors, especially for the d -electronic systems, such correlated electronic structure or quasiparticle spectrum can lead to substantial modification of the EP coupling constant, as originally proposed by Eliashberg [30]. The same effect also leads to a violation of the Migdal's theorem [31]. We treat this problem using a quasiperturbation method in which the noninteracting electron and phonon dispersions are computed via DFT framework. Then the EP coupling vertex is calculated self-consistently in which the electronic state is dressed with both EE (density fluctuations) and EP coupling. The quasiparticle-phonon coupling density of states (DOS) or the so-called $\alpha^2 F$ is calculated as [30,32]

$$\alpha^2 F_p(\omega_p) = \frac{1}{\Omega_{\text{BZ}} \bar{N}(0)} \sum_{\mathbf{q}, \mathbf{k}, v} \text{Tr}[\tilde{V}_p(\mathbf{q}, \omega_p)] \delta(\tilde{\xi}_{\mathbf{k}}^v) \delta(\tilde{\xi}_{\mathbf{k}+\mathbf{q}}^v), \quad (9)$$

where $\bar{N}(0)$ is the correlated electronic DOS at the Fermi level, and the self-energy dressed quasiparticle band is $\tilde{\xi}_{\mathbf{k}}^v = \xi_{\mathbf{k}}^v + \Sigma'_v(\tilde{\xi}_{\mathbf{k}}^v)$, and V_p is defined in Eq. (7) but with self-energy correction. Therefore, the SC transition temperature becomes [32]

$$T_c = \frac{\omega_{\text{log}}}{1.2k_B} \exp\left(-\frac{1.04(1+\lambda)}{\lambda - \mu^*(1+0.62\lambda)}\right), \quad (10)$$

where the traditional Debye frequency is replaced by [33]

$$\omega_{\text{log}} = \exp\left(\frac{2}{\lambda} \int d\omega_p \log \omega_p \frac{\alpha^2 F_p(\omega_p)}{\omega_p}\right), \quad (11)$$

and the EP coupling strength for the Cooper pair is

$$\lambda = 2 \int d\omega_p \frac{\alpha^2 F_p(\omega_p)}{\omega_p}. \quad (12)$$

Note that the EP coupling in the SC channel λ is different from the EP coupling constant for the single particle spectrum $\lambda_{qp} = Z^{-1} - 1$, where $Z^{-1} = 1 - (\partial \Sigma' / \partial \omega)_{\omega=0}$, that one often obtains from the quasiparticle self-energy [34].

The Coulomb pseudopotential μ_0^* is often taken as a parameter, however, the evolution of it in the correlated system and as a function of doping can be estimated as

$$\mu^* = \frac{\mu_0^*}{1 + \mu_0^* \log\left(\frac{\bar{U}}{\omega_{\log}}\right)}, \quad (13)$$

where the renormalized Coulomb interaction is $\bar{U} = U/(1 + \lambda)$. The doping dependent values of ω_{\log} and μ^* are shown in Fig. 8 for both materials.

D. Parameters

The band structure and the phonon spectrum are deduced from first-principles calculations without any adjustable parameter. All other parameters are adjusted only at the optimal doping for the corresponding systems to get the experimental value of T_c . For example, we deduce the Coulomb interactions from the Kanamori criterion from the self-energy dressed “bare” susceptibilities (here bare refers to the susceptibility before invoking RPA effect, but with self-energy). The values are set at the optimal doping, and are kept to be doping independent, but material dependent. The largest interaction value we find is 2 eV for both cases. The EP coupling potential g_0 is found to be 33 meV for MoS₂ and for 35 meV TiSe₂ at their optimal dopings. Finally, for the bare value of μ_0^* in Eq. (13), we use a standard value $\mu_0^* = 0.1$ for both materials. All the other values, such as renormalized ω_{\log} , μ^* , and \bar{U} are computed self-consistently at all dopings using the formulas given above.

III. RESULTS

A. MoS₂ thin flake

For MoS₂, SC is observed in a thin flake sample. As mentioned in Sec. II A above, to simulate a thin flake sample, we use the band structure for the bilayer MoS₂ [see Fig. 2(a)]. In the band insulator MoS₂ at $x = 0$, susceptibility is fully gapped below the particle-hole continuum [Figs. 5(a) and 5(b)], and thus no significant renormalization arises from the EE part. At finite doping, as shown for optimal doping $x = 0.1$ in Figs. 2(b) and 2(c), several new dynamical excitation channels arise at low energy, mainly dominated by the intraband transitions across E_F . The spin channel moves to a lower energy than the charge one, and possesses a larger intensity, giving the largest contribution to the many-body renormalization effect.

We show the doping evolution of all three correlation functions by computing the \mathbf{k} and orbital averaged correlation spectrum, in the same spirit as Eq. (9), for spin and charge fluctuations [34] as $\alpha^2 F_i(\omega_p) = 1/\Omega_{\text{BZ}} \sum_{\mathbf{q}} \text{Tr}[\hat{V}_i(\mathbf{q}, \omega_p)]$. In Fig. 2(d) the total electronic (spin + charge) $\alpha^2 F$ is plotted for several dopings. We find several dominant peaks at all dopings, except at $x = 0$, whose strength increases with

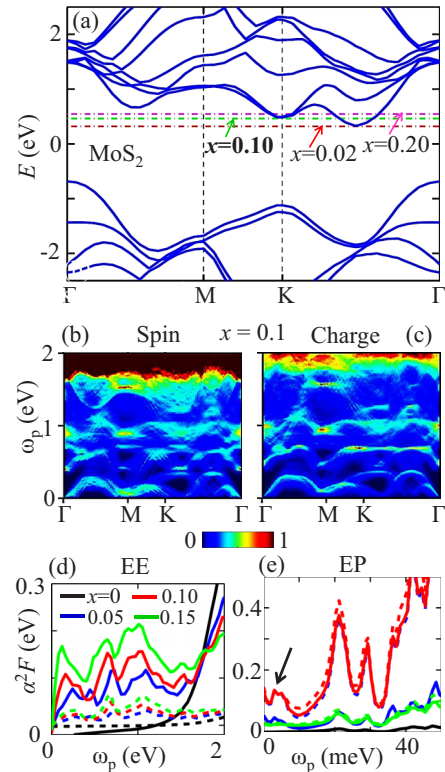


FIG. 2. (Color online) (a) DFT band structure of bilayer MoS₂. (b) and (c) Imaginary part of the spin- and charge-fluctuations ($\chi''_{s/c}$) dispersion along the high-symmetry directions (q), respectively, at optimal doping $x = 0.1$. (d) Self-consistently evaluated electronic $\alpha^2 F(\omega)$ is plotted for various representative dopings. Solid lines are the total value (spin+charge), while the dashed lines are their charge contributions. (e) Doping evolution of the EP coupling $\alpha^2 F$ in the presence of self-consistent EE and EP interactions. Dashed lines are the same self-consistent EP $\alpha^2 F$ but without EE interaction. The arrow dictates the presence of multiple acoustic phonon modes with finite doping.

doping, suggesting that the strength of the EE correlation gradually increases. On the other hand, the EP $\alpha^2 F$, shown in Fig. 2(e), shows maximum intensity at $x = 0.1$. Interestingly, the EP $\alpha^2 F$ without including EE interaction in the electronic spectrum (dashed lines) shows fairly doping independent behavior from underdoped to the optimally doped region. The resulting EP coupling constant λ exhibits a dome feature with doping as shown in the inset to Fig. 1. This result suggests that although superconductivity in MoS₂ is unlikely to have an electronic mechanism, however, the EE correlation is important in renormalizing the EP coupling which in turn governs the SC dome.

In Fig. 3 we present the electronic self-energy and the dressed DOS for MoS₂. The self-energy is presented for the lowest energy band which crosses E_F , and possesses the largest renormalization. The corresponding (k -averaged) mass renormalization factor $m^*/m_b = [1 - \partial \Sigma'(\omega)/\partial \omega]_0^{-1}$ (where m_b is the DFT band mass) is shown in Fig. 1. As expected, the electronic Σ is very weak at $x = 0$. At finite doping, the intraband excitations provide large mass enhancements, reaching a value above 2 at optimal to overdoped region. The EP contribution, shown in Figs. 3(c) and 3(d), remains

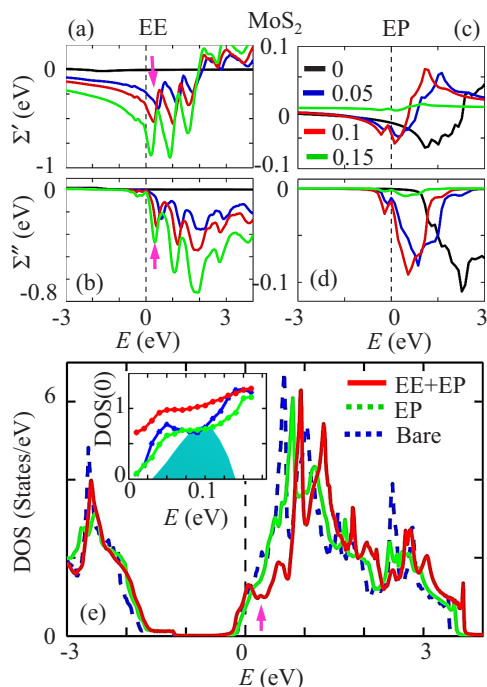


FIG. 3. (Color online) (a) and (b) Real (Σ') and imaginary (Σ'') parts of the EE self-energy at four representative dopings [see legend in (c)]. (c) and (d) Same results, but for EP coupling. (e) DOS at optimal doping. The vertical arrow in (a), (b), and (e) points out that the peak in Σ'' in (d) corresponds to the dip in the DOS in (e). Inset: The doping evolution of the DOS at E_F . Blue symbols are the bare DFT value, while green open circles are DOS with only EP coupling and the red filled circles are the same including both EE and EP interactions. Light blue shading is the theoretical T_c in arbitrary unit.

comparatively weak throughout the phase diagram, however, it reaches a maximum value near the optimal doping. Both EE and EP self-energies show strong particle-hole asymmetry due to the semimetalliclike band structure of this system. The imaginary part of the self-energy Σ'' possesses multiple low-energy peaks, coming from several collective modes in

the susceptibility discussed in Fig. 2. Due to causality, the real part of self-energy Σ' sharply changes slope at energies where Σ'' has peaks.

The self-energy splits the noninteracting DOS into a low-energy quasiparticle peak and a higher-energy incoherent satellite (or hump) feature as seen in the Σ -dressed DOS in Fig. 3(e). This unique self-energy behavior, creating a peak-dip-hump feature, is also observed in cuprates [14] and actinides superconductors [29]. Although, EP self-energy possesses similar energy dependence, however, it fails to create any accountable peak-dip-hump feature in this system due to its weak strength. The spectral weight transfer from the higher energy states to the quasiparticle states at E_F , dictated by the change in DOS between the interacting case (red filled symbol) and noninteracting DOS (blue open circles). This doping dependence of the EE interaction plays a dominant role in creating the domelike doping dependence of T_c , shown in Fig. 1.

We estimate the value of T_c from the renormalized EP $\alpha^2 F$ by using the standard Allen-Dynes formula given in Eq. (10) above. The so-called Debye frequency, which is modified to a renormalized value as ω_{\log} , does not show any significant doping dependence [Figs. 8(c) and 8(d)] [35]. Similarly, the renormalized screened Coulomb potential μ^* also does not possess any significant doping dependence for the constant value of μ_0^* and on-site Coulomb potential U . Using this formula we find that theoretical estimation of T_c quantitatively reproduces the experimental dome [11] when both EE and EP interactions are self-consistently included in the renormalization term. When EE interaction is neglected, but the EP self-energy is included in the renormalized $\alpha^2 F$ spectrum, the calculation overestimates the experimental T_c in the entire phase diagram (also see calculations of EP coupling induced T_c in MoS₂ without including its renormalization in Refs. [36,37]).

B. TiSe₂

Next we study the origin of the SC dome in TiSe₂. In Fig. 4(a) we present our results of T_c , calculated for the case

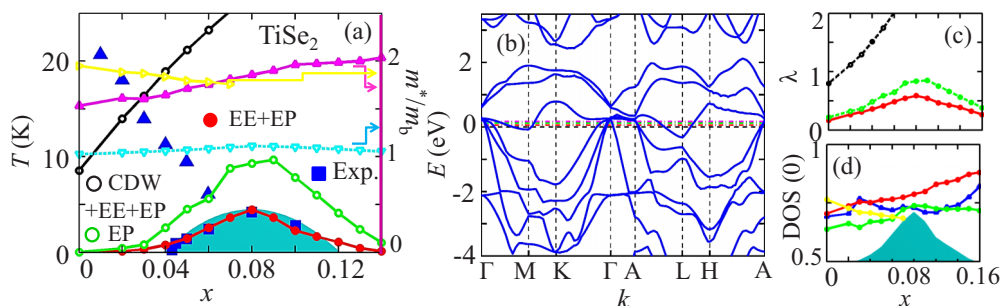


FIG. 4. (Color online) (a) SC phase diagram of TiSe₂. Blue squares are T_c , where blue triangles are $T_{\text{CDW}} (\times 10)$ from Ref. [6]. Red filled and green open circles give computed T_c for the cases of EE+EP and EP only, respectively, but without CDW. Black open circles give T_c when CDW and EE+EP interactions are all self-consistently included. Magenta filled, cyan open, and yellow open triangles give the computed mass enhancement for the three cases discussed above. Light blue shading is a guide to the eyes to the experimental SC dome behavior. (b) DFT band structure in the 3D momentum space (along high-symmetry directions). Different horizontal dashed lines give E_F for $x = 0, 0.04, 0.08$, and 0.12 with increasing values. (c) EP coupling constant for the three cases as discussed in (a) with the same symbols. (d) DOS at E_F for bare (blue open triangles), with only EP interaction (green open circles), with EE and EP interactions (red filled circles), and with CDW ($\times 4$ yellow open circles). Light blue shading is the theoretical T_c in arbitrary unit.

of EP, EE+EP, and with CDW and EE+EP interactions. We include CDW at nesting $\mathbf{Q} = (1/2, 1/2, 1/2)$ as demonstrated experimentally [12], and the mean-field CDW gap is taken to be $\Delta = 13.4k_B T_{\text{CDW}}$ at various dopings, which reasonably reproduces the experimental gap [38]. The self-energy properties and the peak-dip-hump feature in the DOS are all characteristically analogous to MoS₂. Moreover, in TiSe₂ the spin component dominates the fluctuation strength, and then follows the contributions of charge and phonon terms in order.

TiSe₂ is a three-dimensional system with considerable dispersion along the k_z direction as shown in Fig. 4(b). Therefore, the correlation effect is reduced here compared to MoS₂, as evident in the lower mass renormalization seen in Fig. 4(a). As a result, the values of EP coupling constant and T_c with and without including EE interaction are closer to each other in this system. However, the presence of CDW enhances the EP coupling constant above $\lambda > 2$ at the optimal doping, as shown in Fig. 4(c), in which the Migdal theorem is violated [39]. We find that CDW overestimates T_c by about 10–20 times. On the basis of this reasoning, we conclude that CDW and SC are competing in TiSe₂. Our finding is consistent with the conclusions of the x-ray scattering data in 1T-TiSe₂ systems [12], and also with a DFT calculation [40]. Moreover, in QCP induced unconventional superconductors, a linear-in- T dependence of resistivity is observed at the SC dome, which is attributed to non-Fermi liquid behavior. But in TiSe₂, the resistivity data continues to exhibit quadratic T dependence throughout the entire SC dome [6–9], pointing against the existence of a QCP. Therefore, the quasiparticle renormalization and the spectral weight transfer between the quasiparticle state and the high-energy states, driven by spin and charge fluctuations, play a dominant role in reducing T_c in conventional superconductors.

With the same interaction parameters which give good estimation of T_c , we also get mass renormalization in good accord with experiments in both systems. For MoS₂ we find $m^*/m_b \sim 2$ –2.5 in the optimal to overdoped region. The corresponding experimental value, deduced by ARPES [41] with respect to a simple parabolic band, is ~ 2.4 for the hole band. Again for TiSe₂ we estimate the experimental mass renormalization by comparing ARPES data [42] with the DFT band, and find the average value for the two low-lying bands is $m^*/m_b \sim 1.74$, which is close to our result of 1.8–2. It is interesting to notice that despite having similar mass renormalizations, T_c values differ substantially in two systems. This is because EE interaction does not solely determine the value of T_c , but it reduces the EP coupling strength. For MoS₂ at optimal doping, the EP coupling constant without EE interaction is ~ 1.3 which reduces by a factor of ~ 0.53 when the EE interaction is included, and the mass enhancement at the same doping is ~ 2 . For TiSe₂ at optimal doping, these corresponding numbers are 0.85, 0.65, and 1.8, respectively.

IV. CONCLUSION

The main conclusion of this work is that the EP coupling constant is substantially modified by the dynamical EE interactions, which are, in general, tunable via external parameters such as doping, pressure, magnetic field, and others. While the examples are demonstrated here for two families of

conventional superconductors, generalization to other forms of electron-boson coupling, such as spin fluctuation or polaron mediated superconductivity is rather straightforward. Doping a Mott insulator usually weakens the EE correlation strength as seen in cuprates [14]. On the other hand, as demonstrated here, doping enhances EE interactions in the band insulator. In both Mott and band insulators, superconductivity seemingly emerges when the EE interaction strength falls into the intermediate coupling region where sufficient spectral weight is transferred to the quasiparticle states near E_F from the higher energy “incoherent” hump (s) via coupling to dominant spin and charge fluctuations [14,43]. We find that when these EE interactions are taken into account in the EP (or, more appropriately, quasiparticle-phonon) coupling, its strength and T_c are significantly changed and acquires doping dependence. Taken together, our study suggests that as a method of controlling the quasiparticle-boson coupling to optimize T_c , EE interactions may play the common role in creating the SC dome behavior in both conventional and unconventional superconductors.

ACKNOWLEDGMENT

The work is facilitated by the computer clusters at the Graphene Research Center at the National University of Singapore.

APPENDIX A: SPECTRUM OF DENSITY FLUCTUATIONS FOR THIN FLAKE MoS₂ AND TiSe₂

In the band insulating state of MoS₂, both spin and charge susceptibilities, shown in Figs. 5(a) and 5(b), are gapped inside the particle-hole continuum. No collective excitation develops inside the spin gap in a band insulator, unlike in a magnetic insulator where a spin-wave dispersion (Goldstone mode) arises inside the particle-hole continuum due to symmetry breaking (see, e.g., Fig. 6 of Ref. [44]). At finite doping [Figs. 5(c) and 5(d)], in the metallic state, various intraband transitions turn on and give rise to low-energy modes. Some of the modes extend to $\omega_p \rightarrow 0$. The spin channels are moved to lower in energy than the charge counterpart due to the many-body correction within the RPA model. These low-energy modes are responsible for the increase of renormalization effect at finite doping. In TiSe₂ at its optimal doping, due to the presence of many bands in the low-energy spectrum, the density fluctuation channels exhibit several modes, as shown in Figs. 5(g) and 5(h).

APPENDIX B: MOMENTUM AND DOPING DEPENDENT SELF-ENERGY

The momentum dependence of the self-energies is one of the advantages of the present MRDF method, which allows us to understand the origin of the strong correlation feature from the band structure properties. As mentioned before, the density-density fluctuations arise from the JDOS fluctuation, which means it is dominated by the higher DOS regions in both filled and empty states. As seen in Fig. 6, for MoS₂, there is a strong spectral weight of the spin and charge mode

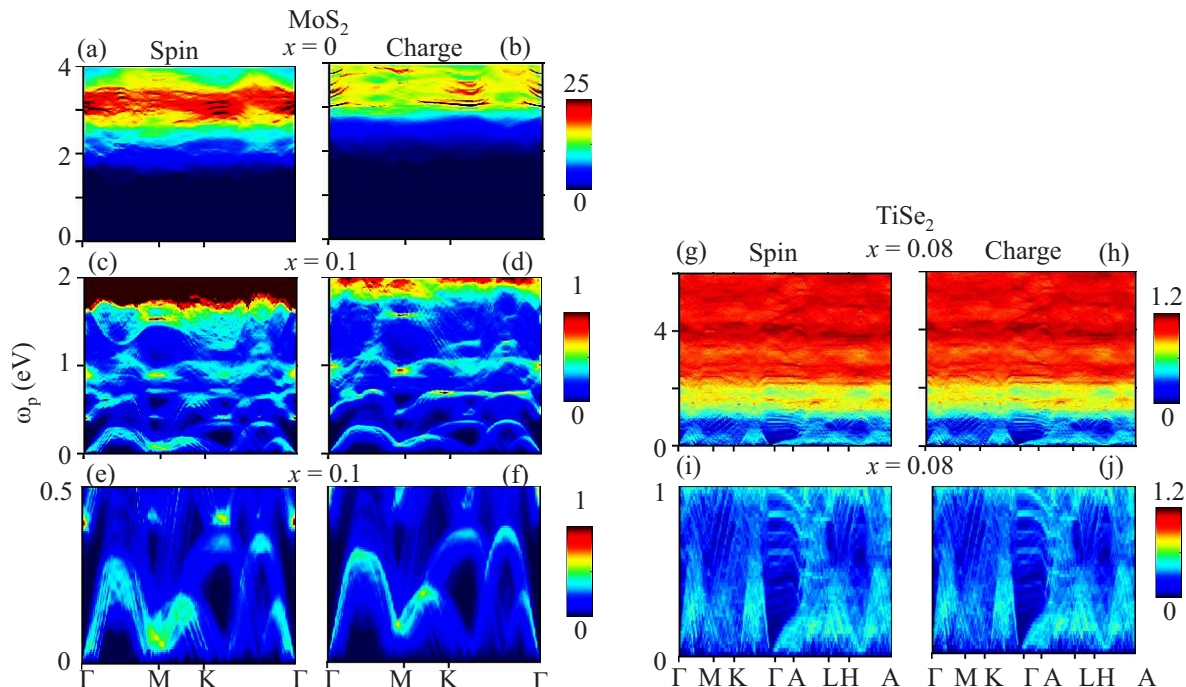


FIG. 5. (Color online) Imaginary parts of the spin and charge susceptibilities for various representative cases. (a) and (b) MoS₂ at $x = 0$. (c) and (d) Same as (a) and (b), but in at the optimal doping. (e) and (f) Zoomed in view of the same data shown in (c) and (d), respectively. (g) and (h) Same data, but for TiSe₂ at its optimal doping. (i) and (j) Zoomed in view of their corresponding upper panels. The results for TiSe₂ are plotted in the log scale for clarity, while that for MoS₂ are plotted in linear scale. All results are shown by summing over all band contributions.

around the $\mathbf{q} = M$ point, which disperses strongly along the Γ point, rather than along the K point. This low-energy mode is mainly responsible for the low-energy band renormalization in the self-energy, see Fig. 7. In both the real and imaginary part of the self-energy, the strongest renormalization appears around $\mathbf{k} = K$ point, where the two bands almost overlap, see Fig. 2, giving rise to higher DOS at the Fermi level. In the right-hand panel of Fig. 6, it is shown that the spin contribution

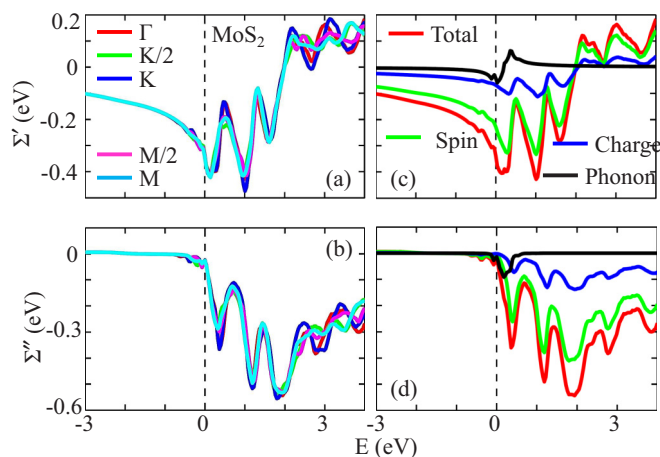


FIG. 6. (Color online) Analysis of various self-energy properties for MoS₂. (a) and (b) Momentum dependence of the real and imaginary parts of total self-energy at optimal doping for the band which crosses the Fermi level. (c) and (d) Various components of the total self-energy at the same doping. As mentioned in the main text, the largest contribution stems from the spin channel.

to the fluctuation spectrum is dominant, and then the charge contribution, while phonon contribution is the least.

The momentum dependence of the self-energy is very weak in TiSe₂, as shown in Fig. 7. This is also reflected in the susceptibility spectrum in Fig. 5 which is quite broad and dispersive. Similarly, the electronic dispersion of this system also indicates that there is not much of an electronic “hot spot” for the strong correlation phenomena. Despite TiSe₂ having a metallic DFT band structure, its self-energy spectrum exhibits

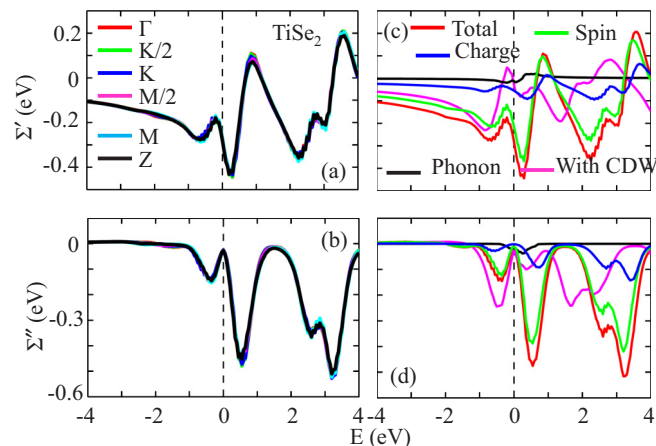


FIG. 7. (Color online) (a) and (b) The momentum dependence of the self-energy is reduced in this system rather than in MoS₂. The three dimensionality of the self-energy is also weak. (c) and (d) As in MoS₂, the spin-density fluctuation is also dominant in TiSe₂. The CDW results are shown for $x = 0.05$.

particle-hole asymmetry. This is due to the fact that the bands are more dispersive below E_F than above it, which makes the correlation effects larger in the empty states.

APPENDIX C: DOPING DEPENDENT m^*/m_b , RENORMALIZED ω_{\log} , AND μ^*

The mass enhancement $m^*/m_b = 1/Z$ at the Fermi level is plotted in the upper panel of Fig. 8 for the highest renormalized band (nearest to the Fermi level) as a function of doping. As shown in Fig. 1, the phonon part (black dots) exhibits a domelike feature centering the optimal doping, while spin and charge contributions increase gradually with doping. As the phonon contribution decreases in the overdoped region, the spin contribution rises sharply. For TiSe_2 , the phonon and charge contributions are very similar as a function of doping. In the CDW state, the renormalization is dominant in the undoped case, and then decreases monotonically with doping. All results are presented for one of the two bands in the low-energy spectrum in which the renormalization effect is strongest. As deduced before, we get $m^*/m_b \sim 2\text{--}2.5$ in the optimal to overdoped region in MoS_2 , which is close to the experimental value of ~ 2.4 for the hole band. Again for TiSe_2 , the experimental value of $m^*/m_b \sim 1.74$ is close to our result of 1.8–2.

As demonstrated in the main text, the self-energy effects on ω_{\log} and μ^* are rather small, and the values remain fairly doping independent, and do not exhibit any apparent anomaly at the optimal doping. More interestingly, the values are almost

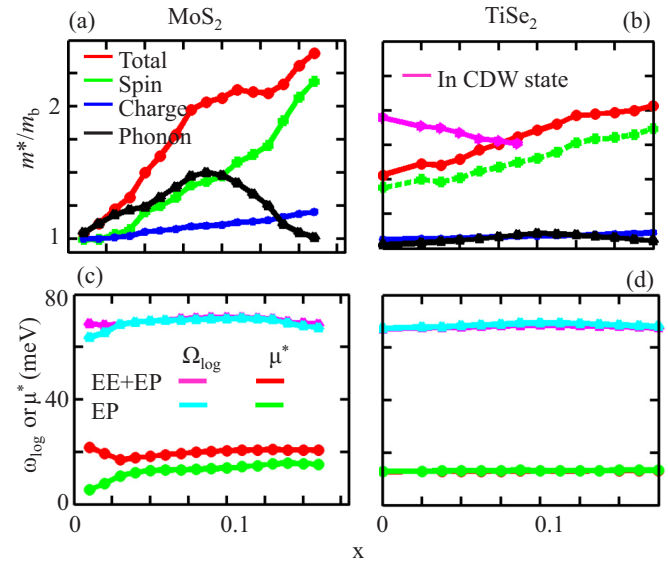


FIG. 8. (Color online) (a) The mass renormalization m^*/m_b at the Fermi level for the highest renormalized band (nearest to the Fermi level) as a function of doping for MoS_2 . (b) Same as (a), but for TiSe_2 . (c) Doping dependence of renormalized ω_{\log} and μ^* for MoS_2 . (d) Same as (c), but for TiSe_2 .

identical for EP and EE+EP cases, demonstrating that these features do not contribute to the formation of the SC dome in these systems.

- [1] L. Taillefer, *Annu. Rev. Condens. Matter Phys.* **1**, 51 (2010).
- [2] S. Deemyad and J. S. Schilling, *Phys. Rev. Lett.* **91**, 167001 (2003).
- [3] J. F. Schooley, W. R. Hosler, E. Ambler, J. H. Becker, Marvin L. Cohen, and C. S. Koonce, *Phys. Rev. Lett.* **14**, 305 (1965); X. Lin, G. Bridoux, A. Gourgout, G. Seyfarth, S. Kramer, M. Nardone, B. Fauque, and K. Behnia, *ibid.* **112**, 207002 (2014).
- [4] A. D. Caviglia, S. Gariglio, N. Reyren, D. Jaccard, T. Schneider, M. Gabay, S. Thiel, G. Hammerl, J. Mannhart, and J.-M. Triscone, *Nature (London)* **456**, 624 (2008).
- [5] K. Shimizu, T. Kimura, S. Furomoto, K. Takeda, K. Kontani, Y. Onuki, and K. Amaya, *Nature (London)* **412**, 316 (2001).
- [6] E. Morosan, H. W. Zandberger, B. S. Dennis, J. W. G. Bos, Y. Onose, T. Klimczuk, A. P. Ramirez, N. P. Ong, and R. J. Cava, *Nat. Phys.* **2**, 544 (2006).
- [7] A. F. Kusmartseva, B. Sipo, H. Berger, L. Forró, and E. Tutis, *Phys. Rev. Lett.* **103**, 236401 (2009).
- [8] H. Suderow, V. G. Tissen, J. P. Brison, J. L. Martinez, and S. Vieira, *Phys. Rev. Lett.* **95**, 117006 (2005); Y. Feng *et al.*, *Proc. Natl. Acad. Sci. USA* **109**, 7224 (2012).
- [9] M. Monteverde, J. Lorenzana, P. Monceau, and M. Núñez-Regueiro, *Phys. Rev. B* **88**, 180504(R) (2013).
- [10] K. Taniguchi, A. Matsumoto, H. Shimotani, and H. Takagi, *Appl. Phys. Lett.* **101**, 042603 (2012).
- [11] J. T. Ye, Y. J. Zhang, R. Akashi, M. S. Bahramy, R. Arita, and Y. Iwasa, *Science* **338**, 1193 (2012).
- [12] Y. I. Joe, X. M. Chen, P. Ghaemi, K. D. Finkelstein, G. A. de la Peña, Y. Gan, J. C. T. Lee, S. Yuan, J. Geck, G. J. MacDougall, T. C. Chiang, S. L. Cooper, E. Fradkin, and P. Abbamonte, *Nat. Phys.* **10**, 421 (2014).
- [13] T. Moriya, *Spin Fluctuations in Electron Magnetism* (Springer, Berlin, 1985).
- [14] T. Das, R. S. Markiewicz, and A. Bansil, *Adv. Phys.* **63**, 151 (2014).
- [15] D. M. Ceperley and B. J. Alder, *Phys. Rev. Lett.* **45**, 566 (1980).
- [16] G. Kresse and J. Furthmüller, *Phys. Rev. B* **54**, 11169 (1996); *Comput. Mater. Sci.* **6**, 15 (1996).
- [17] G. Kresse and D. Joubert, *Phys. Rev. B* **59**, 1758 (1999).
- [18] N. Scheuschner, O. Ochedowski, A.-M. Kaulitz, R. Gillen, M. Schleberger, and J. Maultzsch, *Phys. Rev. B* **89**, 125406 (2014).
- [19] H.-P. Komsa and A. V. Krasheninnikov, *Phys. Rev. B* **86**, 241201 (2012).
- [20] H. Zeng, G.-B. Liu, J. Dai, Y. Yan, B. Zhu, R. He, L. Xie, S. Xu, X. Chen, W. Yao, and X. Cui, *Sci. Rep.* **3**, 1608 (2013).
- [21] X. Gonze, *Phys. Rev. A* **52**, 1086 (1995).
- [22] A. Togo, F. Oba, and I. Tanaka, *Phys. Rev. B* **78**, 134106 (2008).
- [23] A. Splendiani, L. Sun, Y. Zhang, T. Li, J. Kim, C.-Y. Chim, G. Galli, and F. Wang, *Nano Lett.* **10**, 1271 (2010).
- [24] A. Molina-Sanchez, D. Sangalli, K. Hummer, A. Marini, and L. Wirtz, *Phys. Rev. B* **88**, 045412 (2013).
- [25] K. Dolui, I. Rungger, C. Das Pemmaraju, and S. Sanvito, *Phys. Rev. B* **88**, 075420 (2013).

- [26] S. Graser, T. A. Maier, P. J. Hirschfeld, and D. J. Scalapino, *New J. Phys.* **11**, 025015 (2011).
- [27] T. Takimoto, T. Hotta, and K. Ueda, *Phys. Rev. B* **69**, 104504 (2004); K. Kubo, *ibid.* **75**, 224509 (2007).
- [28] L. Hedin and S. Lundqvist, in *Solid State Physics*, edited by R. Seitz, F. Turnbull, and H. Ehrenreich (Academic, New York, 1969), Vol. 15, pp. 1–181; C.-H. Park, F. Giustino, M. L. Cohen, and S. G. Louie, *Phys. Rev. Lett.* **99**, 086804 (2007).
- [29] T. Das, J.-X. Zhu, and M. J. Graf, *Phys. Rev. Lett.* **108**, 017001 (2012).
- [30] G. M. Eliashberg, *Zh. Eksp. Teor. Fiz.* **38**, 966 (1960); **39**, 1437 (1960); *Sov. Phys.-JETP* **11**, 696 (1960); **12**, 1000 (1961).
- [31] J. Bauer, J. E. Han, and O. Gunnarsson, *Phys. Rev. B* **84**, 184531 (2011).
- [32] P. B. Allen and R. C. Dynes, *Phys. Rev. B* **12**, 905 (1975).
- [33] R. C. Dynes, *Solid State Commun.* **10**, 615 (1972).
- [34] R. S. Markiewicz, T. Das, and A. Bansil, *Phys. Rev. B* **86**, 024511 (2012).
- [35] In Ref. [37] the authors have found that ω_{\log} has an opposite doping dependent to EP coupling λ , which together creates a SC dome. After including EE interaction, we find that the doping dependence of the ω_{\log} is significantly reduced.
- [36] Y. Ge and A. Y. Liu, *Phys. Rev. B* **87**, 241408(R) (2013).
- [37] M. Rösner, S. Haas, and T. O. Wehling, *Phys. Rev. B* **90**, 245105 (2014).
- [38] Y. Miyahara, H. Bando, and H. Ozaki, *J. Phys.: Condens. Matter* **7**, 2553 (1995); M. M. May, C. Janowitz, and R. Manzke, [arXiv:1208.4761](https://arxiv.org/abs/1208.4761).
- [39] L. Pietronero, S. Strassler, and C. Grimaldi, *Phys. Rev. B* **52**, 10516 (1995).
- [40] M. Calandra and F. Mauri, *Phys. Rev. Lett.* **106**, 196406 (2011).
- [41] W. Jin, P.-C. Yeh, N. Zaki, D. Zhang, J. T. Sadowski, A. Al-Mahboob, A. M. van der Zande, D. A. Chenet, J. I. Dadap, I. P. Herman, P. Sutter, J. Hone, and R. M. Osgood, Jr., *Phys. Rev. Lett.* **111**, 106801 (2013).
- [42] M. Cazzaniga, H. Cercellier, M. Holzmann, C. Monney, P. Aebi, G. Onida, and V. Olevano, *Phys. Rev. B* **85**, 195111 (2012).
- [43] R. S. Markiewicz, T. Das, and A. Bansil, *Phys. Rev. B* **82**, 224501 (2010).
- [44] T. Das, R. S. Markiewicz, and A. Bansil, *Phys. Rev. B* **85**, 144526 (2012).